

#### **DESCRIPTION**

The SPP6307 is the Dual P-Channel enhancement mode power field effect transistors are produced using high cell density, DMOS trench technology. This high density process is especially tailored to minimize on-state resistance and provide superior switching performance. These devices are particularly suited for low voltage applications such as notebook computer power management and other battery powered circuits where high-side switching, low in-line power loss, and resistance to transients are needed.

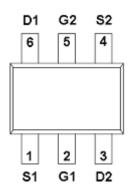
#### **APPLICATIONS**

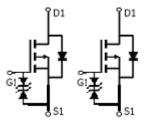
- Drivers : Relays/Solenoids/Lamps/Hammers
- Power Supply Converter Circuits
- Load/Power Switching Cell Phones, Pagers

#### **FEATURES**

- ♦ P-Channel
  - -20V/0.45A, RDS(ON)=  $0.65\Omega$ @VGS=-4.5V
  - -20V/0.35A,RDS(ON)=  $0.90\Omega$ @VGS=-2.5V
  - -20V/0.25A,RDS(ON)=  $1.5\Omega$ @VGS=-1.8V
- Super high density cell design for extremely low RDS (ON)
- Exceptional on-resistance and maximum DC current capability
- ♦ ESD protected
- ♦ SOT-363 package design

### PIN CONFIGURATION (SOT-363)





#### PART MARKING



Y: Year Code W: Week Code

PIN DESCRIPTION						
Pin	Symbol	Description				
1	S1	Source 1				
2	G1	Gate 1				
3	D2	Drain 2				
4	S2	Source 2				
5	G2	Gate 2				
6	D1	Drain1				

### **ORDERING INFORMATION**

Part Number	Package	Part Marking
SPP6307S36RGB	SOT-363	07

<sup>※</sup> SPP6307S36RGB : Tape Reel ; Pb − Free, Halogen − Fre

### ABSOULTE MAXIMUM RATINGS

(Ta=25°C Unless otherwise noted)

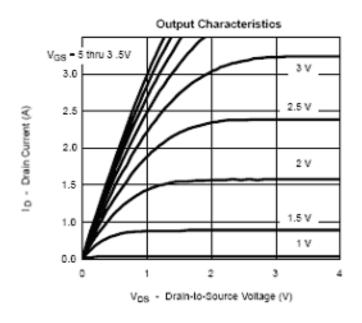
Parameter		Symbol	Typical	Unit	
Drain-Source Voltage		VDSS	-30	V	
Gate –Source Voltage		VGSS	±12	V	
G .: D : G (T- 1500C)	Ta=25°C	т_	-0.45		
Continuous Drain Current(TJ=150°C)	Ta=80°C	ID	-0.35	A	
Pulsed Drain Current		IDM	-1.0	A	
Continuous Source Current(Diode Conduction)		Is	-0.3	A	
5	Ta=25°C	D-	0.27	W	
Power Dissipation	Ta=70°C	PD	0.16		
Operating Junction Temperature		Тл	-55/150	°C	
Storage Temperature Range		Tstg	-55/150	°C	

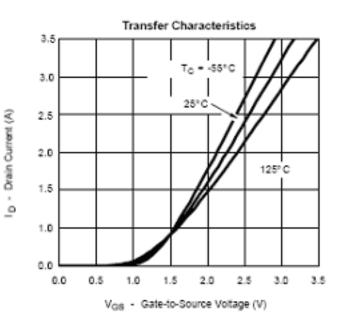
### **ELECTRICAL CHARACTERISTICS**

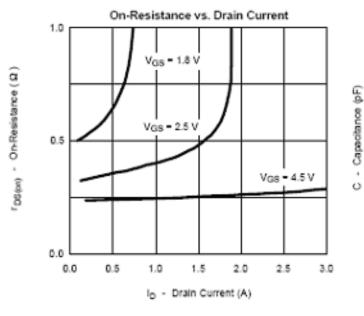
(TA=25°C Unless otherwise noted)

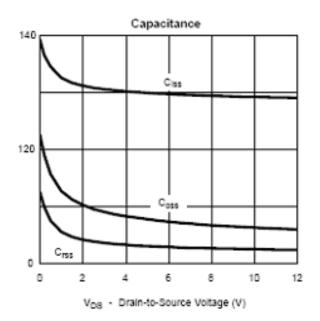
Parameter	Symbol	Conditions	Min.	Тур	Max.	Unit	
Static	•		•		ı		
Drain-Source Breakdown Voltage	V(BR)DSS	Vgs=0V,ID=-250uA	-30			V	
Gate Threshold Voltage	VGS(th)	V <sub>GS(th)</sub> V <sub>DS</sub> =V <sub>GS</sub> ,I <sub>D</sub> =-250uA			-1.0	\ \	
Gate Leakage Current	Igss	VDS=0V,VGS=±12V			±10	uA	
		VDS=-24V,VGS=0V			-1		
Zero Gate Voltage Drain Current	Idss	VDS=-24V,VGS=0V TJ=55°C			-5	uA	
On-State Drain Current	ID(on)	$V_{DS} \le -4.5V, V_{GS} = -5V$	-0.7			A	
	RDS(on)	VGS=-4.5V,ID=-0.45A			0.65	Ω	
Drain-Source On-Resistance		VGS=-2.5V,ID=-0.35A			0.90		
		Vgs=-1.8V,Id=-0.25A			1.50		
Forward Transconductance	gfs	VDS=-10V,ID=-0.25A		0.4		S	
Diode Forward Voltage	Vsd	Is=-0.15A,VGS=0V		-0.8	-1.2	V	
Dynamic							
Total Gate Charge	Qg			1.5	2.0	nC	
Gate-Source Charge	Qgs	VDS=-10V,VGS=-4.5V ID=-0.6A		0.3			
Gate-Drain Charge	Qgd	-100.071		0.35			
Turn-On Time	td(on)			5	10	nS	
	tr	VDD=-10V, RL= $10\Omega$ ,		15	25		
Turn-Off Time	td(off)	ID=-0.4A VGEN=-4.5V, RG=6 $\Omega$		8	15		
	tf			1.4	1.8		

### TYPICAL CHARACTERISTICS

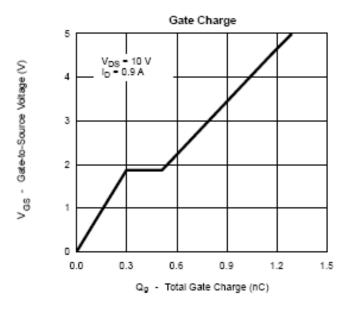


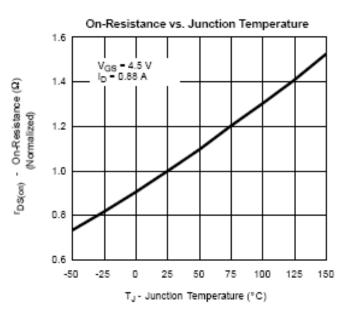


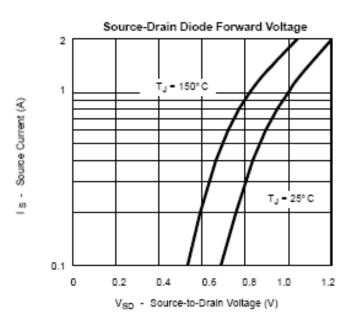


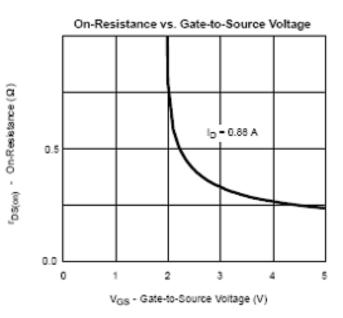


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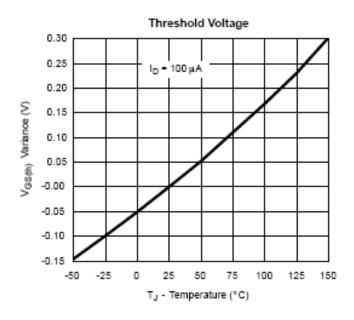


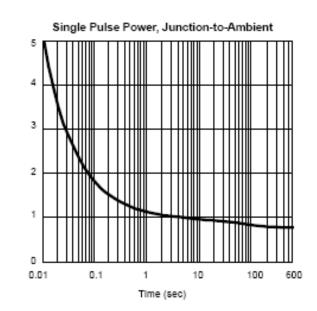


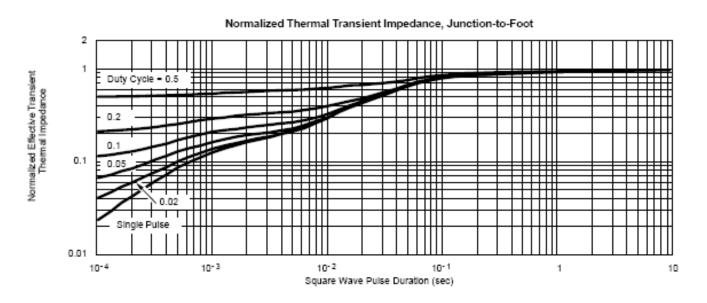




# TYPICAL CHARACTERISTICS







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